NSN 5961-01-420-2329

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Glass
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
32.00 amperes source cutoff current universal and 5.00 microamperes forward current, average peak
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-emitter outside diameter
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0